## NSN 5962-01-185-9615

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Body Length:	
1.290 inches	
Body Width:	
Between 0.500 inches	and 0.610 inches
Body Height:	
0.210 inches	
Maximum Power Dis	sipation Rating:
1.02 watts	
Operating Tempurate	ure Range:
-55.0/+125.0 degrees	celsius
Storage Tempurature	e Range:
-65.0/+150.0 degrees	celsius
End Application:	
Radar system an/fps- <sup>2</sup>	17
Features Provided:	
Hermetically sealed a	nd monolithic and bipolar and programmable and schottky
Inclosure Material:	
Ceramic and glass	
Inclosure Configurat	ion:
Dual-in-line	
Output Logic Form:	
Transistor-transistor lo	ygic
Input Circuit Pattern	
14 input	
Case Outline Source	And Designator:
D-3 mil-m-38510	
Terminal Surface Tre	atment:
Solder	
Voltage Rating And	Type Per Characteristic:
5.5 volts power sourc	e
Time Rating Per Cha	cteristic:
100.00 nanoseconds	propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	r:
Rom	
Memory Capacity:	
Unknown	
Terminal Type And G	luantity:
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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## Demilitarization:

Yes - demil/mli

Fiig:

A458a0

